



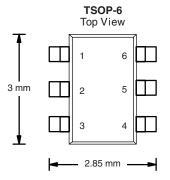
N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)		
30	0.035 at V _{GS} = 10 V	6.0		
	0.052 at V _{GS} = 4.5 V	4.9		

FEATURES

- Halogen free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

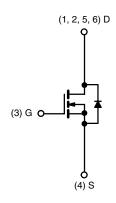




Ordering Information: Si3456BDV-T1-E3 (Lead (Pb)-free)

Si3456BDV-T1-GE3 (Lead (Pb)-free and Halogen-free)

Marking Code: 6Bxxx



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted						
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage	V _{GS}	±				
Continuous Drain Current /T = 150 °C\a	T _A = 25 °C	- I _D	6.0	4.5	_	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		4.8	3.6		
Pulsed Drain Current		I _{DM}	± 30		A	
Continuous Source Current (Diode Conduction) ^a		I _S	1.7	0.9		
Manipular Daviar Disabation 8	T _A = 25 °C	- P _D	2.0	1.1	W	
Maximum Power Dissipation ^a	T _A = 70 °C	' D	1.3	0.7	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		Ô	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Mariana la Ambianta	t ≤ 5 s	R_{thJA}	55	62.5	°C/W
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	92	110	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	28	40	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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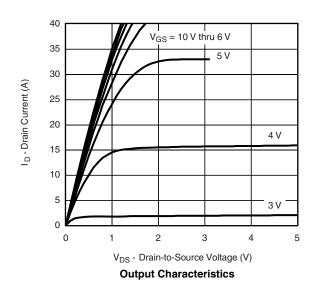
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static	•					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zava Cata Valta va Dusia Comunat	,	V _{DS} = 30 V, V _{GS} = 0 V			1	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	μΑ
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α
		V _{GS} = 10 V, I _D = 6 A		0.028	0.035	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 4.9 \text{ A}$		0.041	0.052	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 6 A		12		S
Diode Forward Voltage ^a	V_{SD}	I _S = 1.7 A, V _{GS} = 0 V		0.8	1.2	V
Dynamic ^b	•					
Total Gate Charge	Qg			8.6	13	
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 6 \text{ A}$		1.8		nC
Gate-Drain Charge	Q _{gd}			1.5		
Gate Resistance	R _g	f = 1 MHz	1.4	2.8	4.8	Ω
Turn-On Delay Time	t _{d(on)}			10	15	
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		15	25	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		25	40	ns
Fall Time	t _f			10	15	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dI/dt = 100 A/μs		20	40	

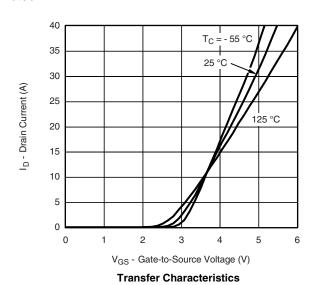
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



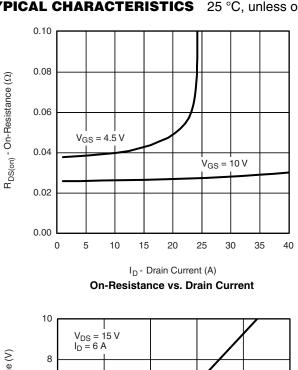


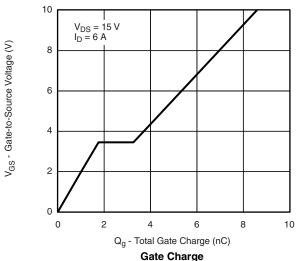


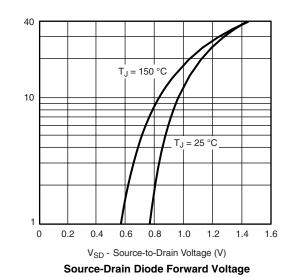


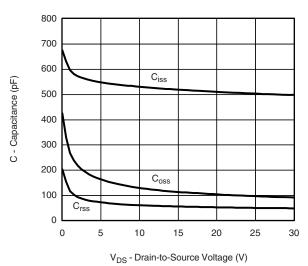


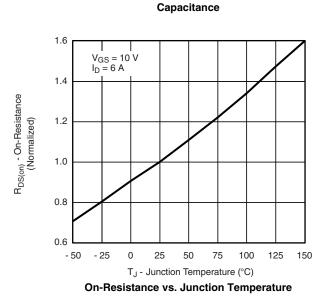
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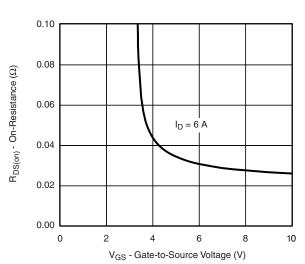












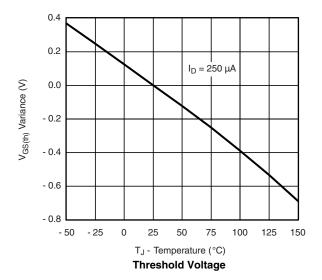
On-Resistance vs. Gate-to-Source Voltage

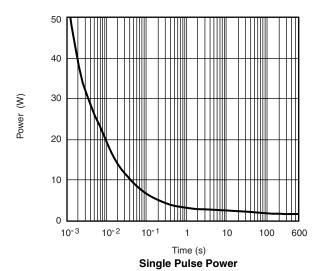
Is - Source Current (A)

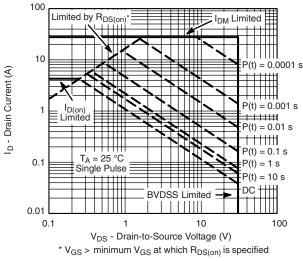
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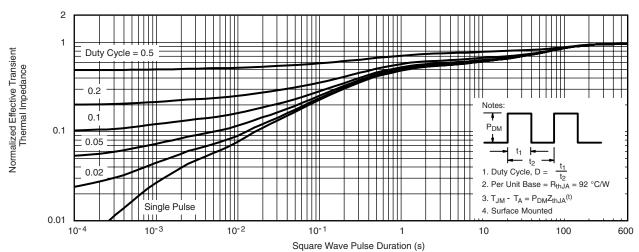
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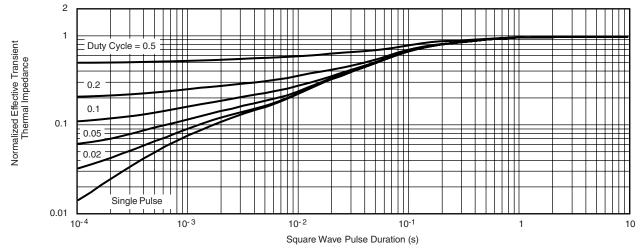
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

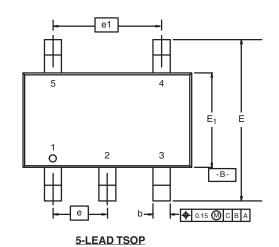
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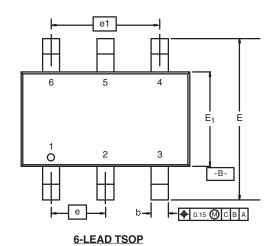


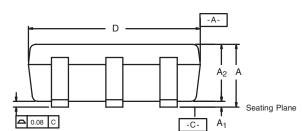


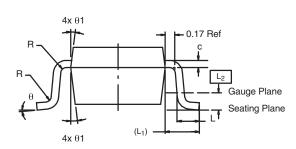
TSOP: 5/6-LEAD

JEDEC Part Number: MO-193C







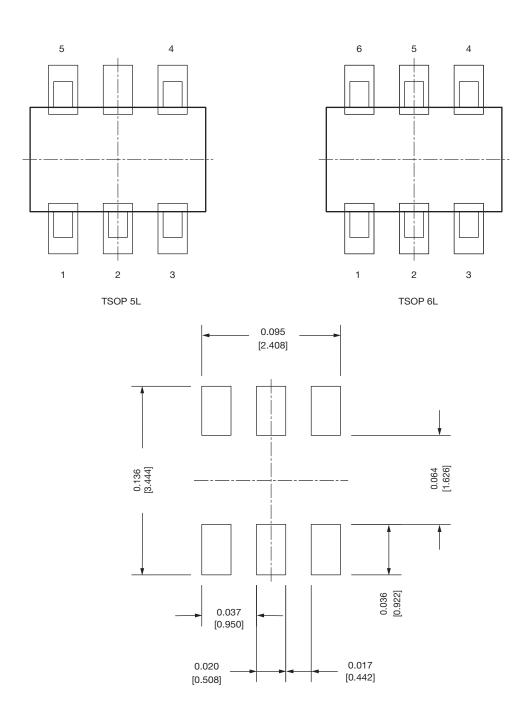


	MIL	LIMETER	RS	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	-	0.043	
A ₁	0.01	-	0.10	0.0004	-	0.004	
A ₂	0.90	-	1.00	0.035	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
E	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е	0.95 BSC			0.0374 BSC			
e ₁	1.80	1.90	2.00	0.071	0.079		
L	0.32	-	0.50	0.012	-	0.020	
L ₁		0.60 Ref		0.024 Ref			
L ₂	0.25 BSC			0.010 BSC			
R	0.10	-	-	0.004	-	-	
θ	0°	4°	8°	0°	4°	8°	
θ_1		7° Nom		7° Nom			
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540							

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Recommended Land Pattern For TSOP-5L / TSOP-6L



Note

• All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010



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